CMOS Digital Integrated Circuits Silicon Monolithic

TC74VCX2541FK

1. Functional Description

Low-Voltage Octal Bus Buffer with 3.6-V Tolerant Inputs and Outputs

2. General

The TC74VCX2541FK is a high-performance CMOS octal bus buffer. Designed for use in 1.8 V, 2.5 V or 3.3 V systems, it achieves high-speed operation while maintaining the CMOS low power dissipation.

It is also designed with overvoltage tolerant inputs and outputs up to 3.6 V.

This device is a non-inverting 3-state buffer having two active-low output enables. When either $\overline{OE1}$ or $\overline{OE2}$ are high, the terminal outputs are in the high-impedance state. This device is designed to be used with 3-state memory address drivers, etc. The 26Ω series resistor helps reducing output overshoot and undershoot without external resistor.

All inputs are equipped with protection circuits against static discharge.

3. Features

- (1) 26Ω series resistors on outputs.
- (2) Low-voltage operation: $V_{\rm CC}$ = 1.8 to 3.6 V
- (3) High-speed operation: $t_{pd} = 4.4$ ns (max) ($V_{CC} = 3.0$ to 3.6 V)

$$t_{pd}$$
 = 5.6 ns (max) (V_{CC} = 2.3 to 2.7 V

$$t_{pd}$$
 = 9.8 ns (max) (V_{CC} = 1.8 V)

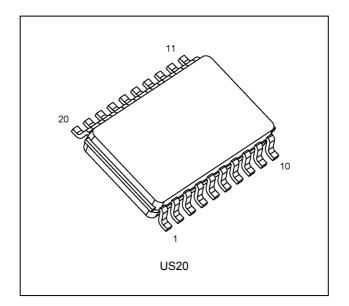
(4) Output current: $I_{OH}/I_{OL} = \pm 12 \text{ mA} \text{ (min)} (V_{CC} = 3.0 \text{ V})$

$$I_{OH}/I_{OL} = \pm 8 \text{ mA} \text{ (min)} (V_{CC} = 2.3 \text{ V})$$

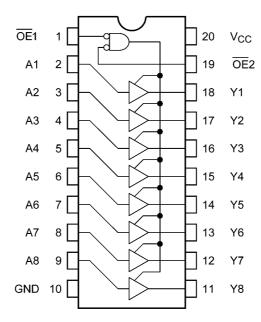
$$I_{OH}/I_{OL} = \pm 4$$
 mA (min) ($V_{CC} = 1.8$ V)

- (5) Latch-up performance: -300 mA
- (6) ESD performance: Human Body Model $\geq \pm 2000 \text{ V}$
- (7) 3.6 V tolerant function and power-down protection provided on all inputs and outputs.

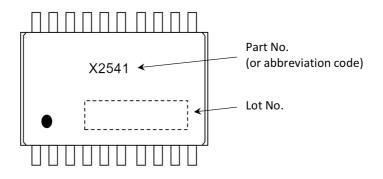
4. Packaging



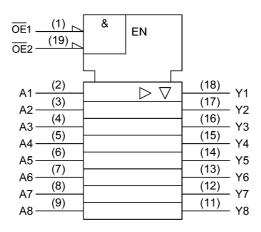
5. Pin Assignment



6. Marking



7. IEC Logic Symbol



8. Truth Table

Input OE1	Input OE2	Inputs An	Outputs
Н	Х	Х	Z
Х	Н	Х	Z
L	L	Н	Н
L	L	L	L

X: Don't care

Z: High impedance

9. Absolute Maximum Ratings (Note)

Characteristics	Symbol	Note	Rating	Unit
Supply voltage	V _{CC}		-0.5 to 4.6	V
Input voltage	V _{IN}		-0.5 to 4.6	V
Output voltage	V _{OUT}	(Note 1)	-0.5 to 4.6	V
		(Note 2)	-0.5 to V _{CC} + 0.5	
Input diode current	I _{IK}		-50	mA
Output diode current	I _{ОК}	(Note 3)	±50	mA
Output current	I _{OUT}		±50	mA
Power dissipation	PD		180	mW
V _{CC} /ground current	I _{CC} /I _{GND}		±100	mA
Storage temperature	T _{stg}		-65 to 150	°C

Note: Exceeding any of the absolute maximum ratings, even briefly, lead to deterioration in IC performance or even destruction.

Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings and the operating ranges.

Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

Note 1: Output in OFF state.

Note 2: High (H) or Low (L) state. I_{OUT} absolute maximum rating must be observed. Note 3: V_{OUT} < GND, V_{OUT} > V_{CC}

10. Operating Ranges (Note)

Characteristics	Symbol	Note	Rating	Unit
Supply voltage	V _{CC}		1.8 to 3.6	V
		(Note 1)	1.2 to 3.6	
Input voltage	V _{IN}		-0.3 to 3.6	V
Output voltage	V _{OUT}	(Note 2)	0 to 3.6	V
		(Note 3)	0 to V _{CC}	
Output current	I _{OH} ,I _{OL}	(Note 4)	±12	mA
		(Note 5)	±8	
		(Note 6)	±4	
Operating temperature	T _{opr}		-40 to 85	°C
Input rise and fall times	dt/dv	(Note 7)	0 to 10	ns/V

Note: The operating ranges must be maintained to ensure the normal operation of the device. Unused inputs must be tied to either V_{CC} or GND.

Note 1: Data retention only.

Note 2: Output in OFF state.

Note 3: High (H) or Low (L) state.

Note 4: V_{CC} = 3.0 to 3.6 V

Note 5: V_{CC} = 2.3 to 2.7 V

Note 6: V_{CC} = 1.8 V

Note 7: V_{IN} = 0.8 to 2.0 V , V_{CC} = 3.0 V

11. Electrical Characteristics

11.1. DC Characteristics (Unless otherwise specified, $T_a = -40$ to 85 °C)

Characteristics	Symbol	Test Condition		V _{CC} (V)	Min	Max	Unit
High-level input voltage	V _{IH}	—		1.8 to 2.3	$V_{CC} imes 0.7$	—	V
				2.3 to 2.7	1.6	_	
				2.7 to 3.6	2.0	—	
Low-level input voltage	VIL	_		1.8 to 2.3	_	$V_{CC} imes 0.2$	V
				2.3 to 2.7	_	0.7	
				2.7 to 3.6	_	0.8	
High-level output voltage	V _{OH}	V _{IN} = V _{IH} or V _{IL}	I _{OH} = -100 μA	1.8 to 3.6	V _{CC} - 0.2	—	V
			I _{OH} = -4 mA	1.8	1.4	—	
				2.3	2.0	—	
			I _{OH} = -6 mA	2.3	1.8	_	
				2.7	2.2	_	
			I _{OH} = -8 mA	2.3	1.7	_	
				3.0	2.4	_	
			I _{OH} = -12 mA	3.0	2.2	_	
Low-level output voltage	V _{OL}	V _{IN} = V _{IH} or V _{IL}	I _{OL} = 100 μA	1.8 to 3.6	_	0.2	V
			I _{OL} = 4 mA	1.8	_	0.3	
			I _{OL} = 6 mA	2.3	_	0.4	
				2,7	_	0.4	
			I _{OL} = 8 mA	2.3	_	0.6	
				3.0	_	0.55	
			I _{OL} = 12 mA	3.0	_	0.8	
Input leakage current	I _{IN}	V _{IN} = 0 to 3.6 V	-	1.2 to 3.6	_	±5.0	μA
3-state output OFF-state leakage current	I _{OZ}	V _{IN} = V _{IH} or V _{IL} V _{OUT} = 0 to 3.6 V		1.2 to 3.6	—	±10.0	μA
Power-OFF leakage current	I _{OFF}	V_{IN}/V_{OUT} = 0 to 3.6 V		0	_	10.0	μA
Quiescent supply current	I _{CC}	V _{IN} = V _{CC} or GND		1.2 to 3.6	_	20.0	μA
		$V_{CC} \le (V_{IN}/V_{OUT}) \le 3.6 \text{ V}$		1.2 to 3.6	_	±20.0	
	Δl _{CC}	V _{IH} = V _{CC} - 0.6 V (per input)		2.7 to 3.6	—	750	μA

11.2. AC Characteristics (Unless otherwise specified, $T_a = -40$ to 85 °C)

Characteristics	Symbol	Note	Test Condition	V _{CC} (V)	Min	Max	Unit
Propagation delay time	t _{PLH} ,t _{PHL}		See 11.5 AC Test Circuit,	1.8	1.5	9.8	ns
			Table 11.5.1, Fig. 11.6.1, Table 11.6.1	2.5 ± 0.2	0.8	5.6	
				3.3 ± 0.3	0.6	4.4	
3-state output enable time	t _{PZL} ,t _{PZH}		See 11.5 AC Test Circuit,	1.8	1.5	9.8	ns
			Table 11.5.1, Fig. 11.6.2, Table 11.6.1		0.8	6.5	
					0.6	5.0	
3-state output disable time	t _{PLZ} ,t _{PHZ}		See 11.5 AC Test Circuit,	1.8	1.5	7.7	ns
			Table 11.5.1, Fig. 11.6.2, Table 11.6.1	2.5 ± 0.2	0.8	4.3	
				$\textbf{3.3}\pm\textbf{0.3}$	0.6	3.9	
Output skew	t _{osLH} ,t _{osHL}	(Note 1)	_	1.8	_	0.5	ns
				2.5 ± 0.2	_	0.5	
				$\textbf{3.3}\pm\textbf{0.3}$	_	0.5	

Note 1: Parameter guaranteed by design. $(t_{osLH} = |t_{PLH}m-t_{PLH}n|, t_{osHL} = |t_{PHL}m-t_{PHL}n|)$

11.3. Dynamic Switching Characteristics (Note) (Unless otherwise specified, $T_a = 25^{\circ}$ C, Input: $t_r = t_f = 2.0$ ns, $C_L = 30$ pF)

Characteristics	Symbol	Test Condition	V _{CC} (V)	Тур.	Unit
Quiet output maximum dynamic V_{OL}	V _{OLP}	V _{IH} = 1.8 V, V _{IL} = 0 V	1.8	0.15	V
		V _{IH} = 2.5 V, V _{IL} = 0 V	2.5	0.25	V
		V _{IH} = 3.3 V, V _{IL} = 0 V	3.3	0.35	
Quiet output minimum dynamic V_{OL}	V _{OLV}	V _{IH} = 1.8 V, V _{IL} = 0 V	1.8	-0.15	V
		V _{IH} = 2.5 V, V _{IL} = 0 V	2.5	-0.25	
		V _{IH} = 3.3 V, V _{IL} = 0 V	3.3	-0.35	
Quiet output minimum dynamic V_{OH}	V _{OHV}	V _{IH} = 1.8 V, V _{IL} = 0 V	1.8	1.55	V
		V _{IH} = 2.5 V, V _{IL} = 0 V	2.5	2.05	
		V _{IH} = 3.3 V, V _{IL} = 0 V	3.3	2.65	

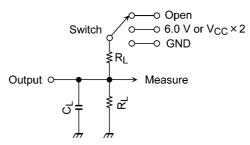
Note: Parameter guaranteed by design.

11.4. Capacitive Characteristics (Unless otherwise specified, $T_a = 25$ °C)

Characteristics	Symbol	Note	Test Condition	V _{CC} (V)	Тур.	Unit
Input capacitance	C _{IN}		—	1.8, 2.5, 3.3	6	pF
Output capacitance	C _{OUT}		—	1.8, 2.5, 3.3	7	pF
Power dissipation capacitance	C _{PD}	(Note 1)	f _{IN} = 10 MHz	1.8, 2.5, 3.3	20	pF

Note 1: C_{PD} is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption without load. Average operating current can be obtained by the equation. $I_{CC(opr)} = C_{PD} \times V_{CC} \times f_{IN} + I_{CC}/8$ (per gate)

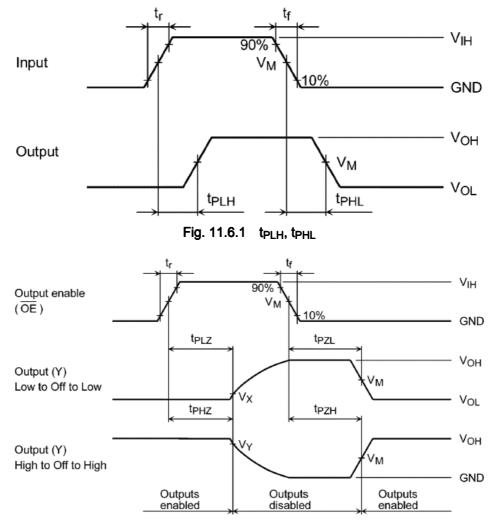
11.5. AC Test Circuit



Parameter	Switch	Test Condition
t _{PLH} , t _{PHL}	OPEN	—
t _{PLZ} , t _{PZL}	6.0 V	V_{CC} = 3.3 \pm 0.3 V
	$V_{CC} \times 2$	V_{CC} = 2.5 \pm 0.2 V
		V _{CC} = 1.8 V
t _{PHZ} , t _{PZH}	GND	—

Table 11.5.1	Parameter for AC	Test Circuit
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11.6. AC Waveform





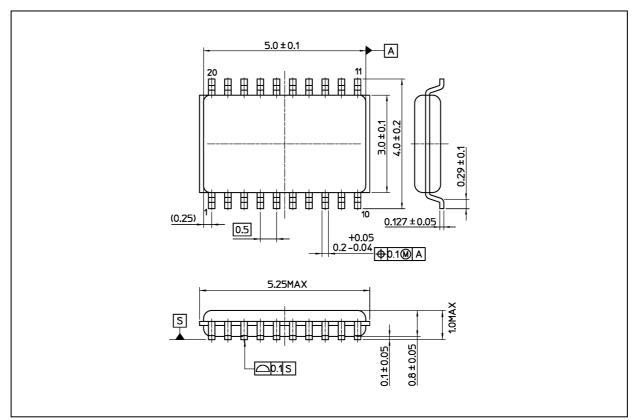
			=	
	Symbol	V_{CC} = 3.3 \pm 0.3 V	V_{CC} = 2.5 \pm 0.2 V	V _{CC} = 1.8 V
Input	V _{IH}	2.7 V	V _{CC}	V _{CC}
	V _M	1.5 V	V _{CC} /2	V _{CC} /2
	t _r , t _f	2.0 ns	2.0 ns	2.0 ns
Output	V _M	1.5 V	V _{CC} /2	V _{CC} /2
	V _X	V _{OL} + 0.3 V	V _{OL} + 0.15 V	V _{OL} + 0.15 V
	V _Y	V _{OH} - 0.3 V	V _{OH} - 0.15 V	V _{OH} - 0.15 V
Load	CL	30 pF	30 pF	15 pF
	RL	500 Ω	500 Ω	2 kΩ

Table 11.6.1 AC Waveform Symbols

TC74VCX2541FK

Package Dimensions

Unit: mm



Weight: 0.03 g (typ.)

	Package Name(s)
Nickname: US20	

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